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#### What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

# Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

### Details

Details	
Product Status	Discontinued at Digi-Key
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	CANbus, I <sup>2</sup> C, IrDA, LINbus, SmartCard, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I <sup>2</sup> S, POR, PWM, WDT
Number of I/O	53
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.8V
Data Converters	A/D 12bit SAR; D/A 12bit
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-TQFP
Supplier Device Package	64-TQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm32tg11b140f64gq64-ar

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

### 3.8.1 Analog Port (APORT)

The Analog Port (APORT) is an analog interconnect matrix allowing access to many analog modules on a flexible selection of pins. Each APORT bus consists of analog switches connected to a common wire. Since many clients can operate differentially, buses are grouped by X/Y pairs.

### 3.8.2 Analog Comparator (ACMP)

The Analog Comparator is used to compare the voltage of two analog inputs, with a digital output indicating which input voltage is higher. Inputs are selected from among internal references and external pins. The tradeoff between response time and current consumption is configurable by software. Two 6-bit reference dividers allow for a wide range of internally-programmable reference sources. The ACMP can also be used to monitor the supply voltage. An interrupt can be generated when the supply falls below or rises above the programmable threshold.

### 3.8.3 Analog to Digital Converter (ADC)

The ADC is a Successive Approximation Register (SAR) architecture, with a resolution of up to 12 bits at up to 1 Msps. The output sample resolution is configurable and additional resolution is possible using integrated hardware for averaging over multiple samples. The ADC includes integrated voltage references and an integrated temperature sensor. Inputs are selectable from a wide range of sources, including pins configurable as either single-ended or differential.

### 3.8.4 Capacitive Sense (CSEN)

The CSEN module is a dedicated Capacitive Sensing block for implementing touch-sensitive user interface elements such a switches and sliders. The CSEN module uses a charge ramping measurement technique, which provides robust sensing even in adverse conditions including radiated noise and moisture. The module can be configured to take measurements on a single port pin or scan through multiple pins and store results to memory through DMA. Several channels can also be shorted together to measure the combined capacitance or implement wake-on-touch from very low energy modes. Hardware includes a digital accumulator and an averaging filter, as well as digital threshold comparators to reduce software overhead.

### 3.8.5 Digital to Analog Converter (VDAC)

The Digital to Analog Converter (VDAC) can convert a digital value to an analog output voltage. The VDAC is a fully differential, 500 ksps, 12-bit converter. The opamps are used in conjunction with the VDAC, to provide output buffering. One opamp is used per singleended channel, or two opamps are used to provide differential outputs. The VDAC may be used for a number of different applications such as sensor interfaces or sound output. The VDAC can generate high-resolution analog signals while the MCU is operating at low frequencies and with low total power consumption. Using DMA and a timer, the VDAC can be used to generate waveforms without any CPU intervention. The VDAC is available in all energy modes down to and including EM3.

### 3.8.6 Operational Amplifiers

The opamps are low power amplifiers with a high degree of flexibility targeting a wide variety of standard opamp application areas, and are available down to EM3. With flexible built-in programming for gain and interconnection they can be configured to support multiple common opamp functions. All pins are also available externally for filter configurations. Each opamp has a rail to rail input and a rail to rail output. They can be used in conjunction with the VDAC module or in stand-alone configurations. The opamps save energy, PCB space, and cost as compared with standalone opamps because they are integrated on-chip.

### 3.8.7 Liquid Crystal Display Driver (LCD)

The LCD driver is capable of driving a segmented LCD display with up to 8x32 segments. A voltage boost function enables it to provide the LCD display with higher voltage than the supply voltage for the device. A patented charge redistribution driver can reduce the LCD module supply current by up to 40%. In addition, an animation feature can run custom animations on the LCD display without any CPU intervention. The LCD driver can also remain active even in Energy Mode 2 and provides a Frame Counter interrupt that can wake-up the device on a regular basis for updating data.

#### 3.9 Reset Management Unit (RMU)

The RMU is responsible for handling reset of the EFM32TG11. A wide range of reset sources are available, including several power supply monitors, pin reset, software controlled reset, core lockup reset, and watchdog reset.

### 4.1.6 Current Consumption

## 4.1.6.1 Current Consumption 3.3 V without DC-DC Converter

Unless otherwise indicated, typical conditions are: VREGVDD = AVDD = DVDD = 3.3 V. T = 25 °C. DCDC is off. Minimum and maximum values in this table represent the worst conditions across supply voltage and process variation at T = 25 °C.

# Table 4.6. Current Consumption 3.3 V without DC-DC Converter

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Current consumption in EM0 mode with all peripherals dis- abled	I <sub>ACTIVE</sub>	48 MHz crystal, CPU running while loop from flash	_	45	_	µA/MHz
		48 MHz HFRCO, CPU running while loop from flash		44	TBD	µA/MHz
		48 MHz HFRCO, CPU running Prime from flash		57		µA/MHz
		48 MHz HFRCO, CPU running CoreMark loop from flash		71	_	µA/MHz
		32 MHz HFRCO, CPU running while loop from flash		45	_	µA/MHz
		26 MHz HFRCO, CPU running while loop from flash		46	TBD	µA/MHz
		16 MHz HFRCO, CPU running while loop from flash		50		µA/MHz
		1 MHz HFRCO, CPU running while loop from flash	—	161	TBD	µA/MHz
Current consumption in EM0 mode with all peripherals dis-	IACTIVE_VS	19 MHz HFRCO, CPU running while loop from flash	—	41	_	µA/MHz
abled and voltage scaling enabled		1 MHz HFRCO, CPU running while loop from flash	_	145	_	µA/MHz
Current consumption in EM1	I <sub>EM1</sub>	48 MHz crystal	—	34	_	µA/MHz
mode with all peripherals disabled		48 MHz HFRCO	—	33	TBD	µA/MHz
		32 MHz HFRCO	—	34		µA/MHz
		26 MHz HFRCO	—	35	TBD	µA/MHz
		16 MHz HFRCO	—	39	_	µA/MHz
		1 MHz HFRCO	—	150	TBD	µA/MHz
Current consumption in EM1	I <sub>EM1_VS</sub>	19 MHz HFRCO	—	32	_	µA/MHz
mode with all peripherals dis- abled and voltage scaling enabled		1 MHz HFRCO	_	136		µA/MHz
Current consumption in EM2 mode, with voltage scaling enabled	IEM2_VS	Full 32 kB RAM retention and RTCC running from LFXO		1.48	_	μA
		Full 32 kB RAM retention and RTCC running from LFRCO	_	1.86		μA
		8 kB (1 bank) RAM retention and RTCC running from LFRCO <sup>2</sup>		1.59	TBD	μΑ
Current consumption in EM3 mode, with voltage scaling enabled	I <sub>EM3_VS</sub>	Full 32 kB RAM retention and CRYOTIMER running from ULFR- CO		1.23	TBD	μA

# 4.1.9 Oscillators

# 4.1.9.1 Low-Frequency Crystal Oscillator (LFXO)

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit
Crystal frequency	f <sub>LFXO</sub>		_	32.768	_	kHz
Supported crystal equivalent series resistance (ESR)	ESR <sub>LFXO</sub>		-	-	70	kΩ
Supported range of crystal load capacitance <sup>1</sup>	C <sub>LFXO_CL</sub>		6	_	18	pF
On-chip tuning cap range <sup>2</sup>	C <sub>LFXO_T</sub>	On each of LFXTAL_N and LFXTAL_P pins	8	-	40	pF
On-chip tuning cap step size	SS <sub>LFXO</sub>		_	0.25	_	pF
Current consumption after startup <sup>3</sup>	I <sub>LFXO</sub>	ESR = 70 kOhm, $C_L$ = 7 pF, GAIN <sup>4</sup> = 2, AGC <sup>4</sup> = 1	_	273	_	nA
Start- up time	t <sub>LFXO</sub>	ESR = 70 kOhm, $C_L$ = 7 pF, GAIN <sup>4</sup> = 2	-	308	_	ms

Note:

1. Total load capacitance as seen by the crystal.

2. The effective load capacitance seen by the crystal will be C<sub>LFXO\_T</sub> /2. This is because each XTAL pin has a tuning cap and the two caps will be seen in series by the crystal.

3. Block is supplied by AVDD if ANASW = 0, or DVDD if ANASW=1 in EMU\_PWRCTRL register.

4. In CMU\_LFXOCTRL register.

# 4.1.12 Voltage Monitor (VMON)

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit
Supply current (including I_SENSE)	I <sub>VMON</sub>	In EM0 or EM1, 1 supply monitored, T $\leq$ 85 °C	_	6.3	TBD	μA
		In EM0 or EM1, 4 supplies monitored, T $\leq$ 85 °C	—	12.5	TBD	μA
		In EM2, EM3 or EM4, 1 supply monitored and above threshold	—	62		nA
		In EM2, EM3 or EM4, 1 supply monitored and below threshold	_	62	_	nA
		In EM2, EM3 or EM4, 4 supplies monitored and all above threshold	_	99	_	nA
		In EM2, EM3 or EM4, 4 supplies monitored and all below threshold	—	99	_	nA
Loading of monitored supply	I <sub>SENSE</sub>	In EM0 or EM1	—	2	_	μA
		In EM2, EM3 or EM4	_	2	_	nA
Threshold range	V <sub>VMON_RANGE</sub>		1.62	_	3.4	V
Threshold step size	N <sub>VMON_STESP</sub>	Coarse	_	200		mV
		Fine	_	20	_	mV
Response time	t <sub>VMON_RES</sub>	Supply drops at 1V/µs rate	_	460	_	ns
Hysteresis	V <sub>VMON_HYST</sub>			26	_	mV

# Table 4.19. Voltage Monitor (VMON)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
SCLK period <sup>1 3 2</sup>	t <sub>SCLK</sub>		6 * <sup>t</sup> HFPERCLK	_	—	ns
SCLK high time <sup>1 3 2</sup>	t <sub>SCLK_HI</sub>		2.5 * t <sub>HFPERCLK</sub>	—	_	ns
SCLK low time <sup>1 3 2</sup>	t <sub>SCLK_LO</sub>		2.5 * <sup>t</sup> HFPERCLK	—	_	ns
CS active to MISO <sup>1 3</sup>	t <sub>cs_аст_мі</sub>		20	—	70	ns
CS disable to MISO <sup>1 3</sup>	t <sub>cs_dis_мi</sub>		15	_	150	ns
MOSI setup time <sup>1 3</sup>	t <sub>su_мо</sub>		4	—	—	ns
MOSI hold time <sup>1 3 2</sup>	t <sub>H_MO</sub>		7		_	ns
SCLK to MISO <sup>1 3 2</sup>	t <sub>SCLK_MI</sub>		14 + 1.5 * t <sub>HFPERCLK</sub>	—	40 + 2.5 * t <sub>HFPERCLK</sub>	ns

# Table 4.32. SPI Slave Timing

### Note:

1. Applies for both CLKPHA = 0 and CLKPHA = 1 (figure only shows CLKPHA = 0).

2.  $t_{\mbox{\scriptsize HFPERCLK}}$  is one period of the selected  $\mbox{\scriptsize HFPERCLK}.$ 

3. Measurement done with 8 pF output loading at 10% and 90% of  $V_{DD}$  (figure shows 50% of  $V_{DD}$ ).

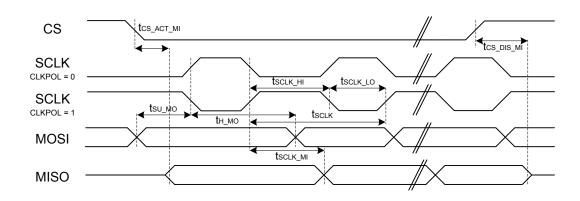


Figure 4.2. SPI Slave Timing Diagram

# 4.2 Typical Performance Curves

Typical performance curves indicate typical characterized performance under the stated conditions.

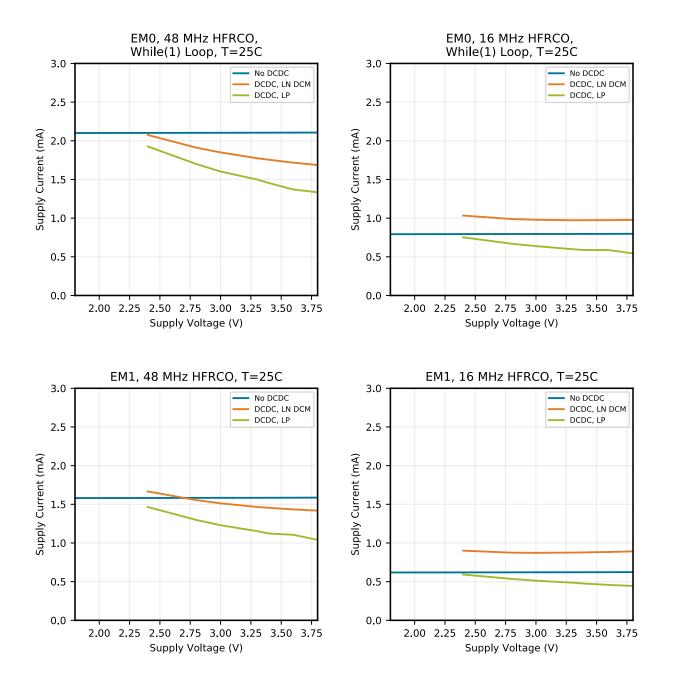
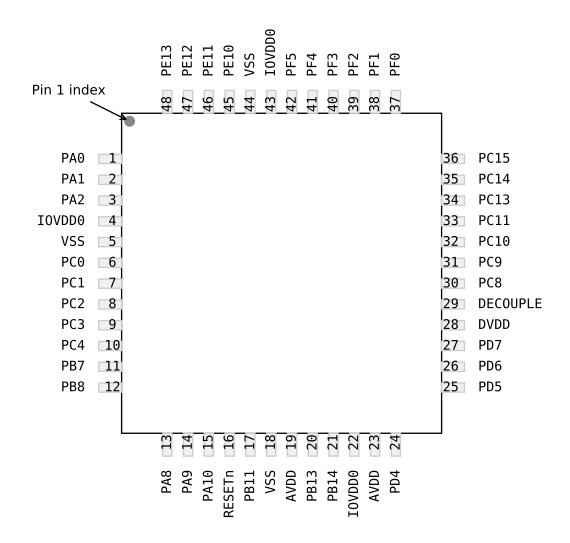


Figure 4.6. EM0 and EM1 Mode Typical Supply Current vs. Supply

Typical supply current for EM2, EM3 and EM4H using standard software libraries from Silicon Laboratories.



### Figure 5.11. EFM32TG11B1xx in QFP48 Device Pinout

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see 5.14 GPIO Functionality Table or 5.15 Alternate Functionality Overview.

Table 5.11. E	EFM32TG11B1xx in	QFP48	Device Pinout
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Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PA0	1	GPIO	PA1	2	GPIO
PA2	3	GPIO	IOVDD0	4 22 43	Digital IO power supply 0.
VSS	5 18 44	Ground	PC0	6	GPIO (5V)
PC1	7	GPIO (5V)	PC2	8	GPIO (5V)
PC3	9	GPIO (5V)	PC4	10	GPIO

Alternate	LOCA	ATION	
Functionality	0 - 3	4 - 7	Description
LCD_COM0	0: PE4		LCD driver common line number 0.
LCD_COM1	0: PE5		LCD driver common line number 1.
LCD_COM2	0: PE6		LCD driver common line number 2.
LCD_COM3	0: PE7		LCD driver common line number 3.
LCD_SEG0	0: PF2		LCD segment line 0.
LCD_SEG1	0: PF3		LCD segment line 1.
LCD_SEG2	0: PF4		LCD segment line 2.
LCD_SEG3	0: PF5		LCD segment line 3.
LCD_SEG4	0: PE8		LCD segment line 4.
LCD_SEG5	0: PE9		LCD segment line 5.
LCD_SEG6	0: PE10		LCD segment line 6.
LCD_SEG7	0: PE11		LCD segment line 7.
LCD_SEG8	0: PE12		LCD segment line 8.

Alternate Functionality	LOCA 0 - 3	ATION 4 - 7	Description
LCD_SEG22 / LCD_COM6	0: PB5		LCD segment line 22. This pin may also be used as LCD COM line 6
LCD_SEG23 / LCD_COM7	0: PB6		LCD segment line 23. This pin may also be used as LCD COM line 7
LCD_SEG24	0: PC4		LCD segment line 24.
LCD_SEG25	0: PC5		LCD segment line 25.
LCD_SEG26	0: PA9		LCD segment line 26.
LCD_SEG27	0: PA10		LCD segment line 27.
LCD_SEG28	0: PB11		LCD segment line 28.
LCD_SEG29	0: PB12		LCD segment line 29.
LCD_SEG30	0: PD3		LCD segment line 30.
LCD_SEG31	0: PD4		LCD segment line 31.
LCD_SEG32	0: PC6		LCD segment line 32.
LCD_SEG33	0: PC7		LCD segment line 33.
LCD_SEG34	0: PC8		LCD segment line 34.

Alternate	LOC	ATION	
Functionality	0 - 3	4 - 7	Description
U0_TX	2: PA3 3: PC14	4: PC4 5: PF1 6: PD7	UART0 Transmit output. Also used as receive input in half duplex communication.
US0_CLK	0: PE12 1: PE5 2: PC9 3: PC15	4: PB13 5: PA12	USART0 clock input / output.
US0_CS	0: PE13 1: PE4 2: PC8 3: PC14	4: PB14 5: PA13	USART0 chip select input / output.
US0_CTS	0: PE14 2: PC7 3: PC13	4: PB6 5: PB11	USART0 Clear To Send hardware flow control input.
US0_RTS	0: PE15 2: PC6 3: PC12	4: PB5 5: PD6	USART0 Request To Send hardware flow control output.
US0_RX	0: PE11 1: PE6 2: PC10 3: PE12	4: PB8 5: PC1	USART0 Asynchronous Receive. USART0 Synchronous mode Master Input / Slave Output (MISO).
US0_TX	0: PE10 1: PE7 2: PC11 3: PE13	4: PB7 5: PC0	USART0 Asynchronous Transmit. Also used as receive input in half duplex communica- tion. USART0 Synchronous mode Master Output / Slave Input (MOSI).
US1_CLK	0: PB7 1: PD2 2: PF0 3: PC15	4: PC3 5: PB11 6: PE5	USART1 clock input / output.
US1_CS	0: PB8 1: PD3 2: PF1 3: PC14	4: PC0 5: PE4	USART1 chip select input / output.
US1_CTS	1: PD4 2: PF3 3: PC6	4: PC12 5: PB13	USART1 Clear To Send hardware flow control input.
US1_RTS	1: PD5 2: PF4 3: PC7	4: PC13 5: PB14	USART1 Request To Send hardware flow control output.
US1_RX	0: PC1 1: PD1 2: PD6	4: PC2 5: PA0 6: PA2	USART1 Asynchronous Receive. USART1 Synchronous mode Master Input / Slave Output (MISO).
US1_TX	0: PC0 1: PD0 2: PD7	4: PC1 5: PF2 6: PA14	USART1 Asynchronous Transmit. Also used as receive input in half duplex communica- tion. USART1 Synchronous mode Master Output / Slave Input (MOSI).

Alternate	LOC	ATION	
Functionality	0 - 3	4 - 7	Description
US2_CLK	0: PC4 1: PB5 2: PA9 3: PA15	5: PF2	USART2 clock input / output.
US2_CS	0: PC5 1: PB6 2: PA10 3: PB11	5: PF5	USART2 chip select input / output.
US2_CTS	0: PC1 1: PB12	4: PC12 5: PD6	USART2 Clear To Send hardware flow control input.
US2_RTS	0: PC0 2: PA12 3: PC14	4: PC13 5: PD8	USART2 Request To Send hardware flow control output.
US2_RX	0: PC3 1: PB4 2: PA8 3: PA14	5: PF1	USART2 Asynchronous Receive. USART2 Synchronous mode Master Input / Slave Output (MISO).
US2_TX	0: PC2 1: PB3 3: PA13	5: PF0	USART2 Asynchronous Transmit. Also used as receive input in half duplex communica- tion. USART2 Synchronous mode Master Output / Slave Input (MOSI).
US3_CLK	0: PA2 1: PD7 2: PD4		USART3 clock input / output.
US3_CS	0: PA3 1: PE4 2: PC14 3: PC0		USART3 chip select input / output.
US3_CTS	0: PA4 1: PE5 2: PD6		USART3 Clear To Send hardware flow control input.
US3_RTS	0: PA5 1: PC1 2: PA14 3: PC15		USART3 Request To Send hardware flow control output.
US3_RX	0: PA1 1: PE7 2: PB7		USART3 Asynchronous Receive. USART3 Synchronous mode Master Input / Slave Output (MISO).
US3_TX	0: PA0 1: PE6 2: PB3		USART3 Asynchronous Transmit. Also used as receive input in half duplex communica- tion. USART3 Synchronous mode Master Output / Slave Input (MOSI).
VDAC0_EXT	0: PD6		Digital to analog converter VDAC0 external reference input pin.

Alternate	LOC	ATION	
Functionality	0 - 3	4 - 7	Description
WTIM1_CC3	0: PD1 1: PD5 2: PC6	4: PE6	Wide timer 1 Capture Compare input / output channel 3.

Port	Bus	CH31	CH30	CH29	CH28	CH27	CH26	CH25	CH24	CH23	CH22	CH21	CH20	CH19	CH18	CH17	CH16	CH15	CH14	CH13	CH12	CH11	CH10	CH9	CH8	CH7	CH6	CH5	CH4	CH3	CH2	CH1	CH0
APORT0X	BUSACMP1X																									PC15	PC14	PC13	PC12	PC11	PC10	PC9	PC8
APORT0Y	<b>BUSACMP1Y</b>																									PC15	PC14	PC13	PC12	PC11	PC10	PC9	PC8
APORT1X	BUSAX		PB14		PB12						PB6		PB4						PA14				PA10				PA6		PA4		PA2		PAO
APORT1Y	BUSAY			PB13		PB11						PB5		PB3				PA15		PA13				PA9				PA5		PA3		PA1	
APORT2X	BUSBX			PB13		PB11						PB5		PB3				PA15		PA13				PA9				PA5		PA3		PA1	
APORT2Y	BUSBY		PB14		PB12						PB6		PB4						PA14				PA10				PA6		PA4		PA2		PA0
APORT3X	BUSCX												PF4		PF2		PF0		PE14		PE12		PE10		PE8		PE6		PE4				
APORT3Y	BUSCY											PF5		PF3		PF1		PE15		PE13		PE11		PE9		PE7		PE5					
APORT4X	BUSDX											PF5		PF3		PF1		PE15		PE13		PE11		PE9		PE7		PE5					
APORT4Y	BUSDY												PF4		PF2		PF0		PE14		PE12		PE10		PE8		PE6		PE4				

# Table 5.17. ACMP1 Bus and Pin Mapping

Port	Bus	CH31	CH30	CH29	CH28	CH27	CH26	CH25	CH24	CH23	CH22	CH21	CH20	CH19	CH18	CH17	CH16	CH15	CH14	CH13	CH12	CH11	CH10	СН9	CH8	CH7	CH6	CH5	CH4	CH3	CH2	CH1	CH0
CE	CEXT																																
APORT1X	BUSAX		PB14		PB12						PB6		PB4						PA14				PA10				PA6		PA4		PA2		PA0
APORT1Y	BUSAY			PB13		PB11						PB5		PB3				PA15		PA13				6Yd				PA5		PA3		PA1	
APORT3X	BUSCX												PF4		PF2		PF0		PE14		PE12		PE10		PE8		PE6		PE4				
APORT3Y	BUSCY											PF5		PF3		PF1		PE15		PE13		PE11		PE9		PE7		PE5					
CE	хт_	SEN	ISE																														
APORT2X	BUSBX			PB13		PB11						PB5		PB3				PA15		PA13				6Yd				PA5		PA3		PA1	
APORT2Y	BUSBY		PB14		PB12						PB6		PB4						PA14				PA10				PA6		PA4		PA2		PAO
APORT4X	BUSDX											PF5		PF3		PF1		PE15		PE13		PE11		PE9		PE7		PE5					
APORT4Y	BUSDY												PF4		PF2		PF0		PE14		PE12		PE10		PE8		PE6		PE4				

# Table 5.19. CSEN Bus and Pin Mapping

Dimension	Min	Тур	Мах								
A	_	_	1.20								
A1	0.05	—	0.15								
A2	0.95	1.00	1.05								
b	0.17	0.20	0.27								
С	0.09	—	0.20								
D		14.00 BSC									
D1	12.00 BSC										
е	0.50 BSC										
E	14.00 BSC										
E1		12.00 BSC									
L	0.45	0.60	0.75								
L1		1.00 REF									
θ	0	3.5	7								
ааа		0.20									
bbb		0.20									
ссс		0.08									
ddd		0.08									
eee	0.05										
Note:											

### Table 6.1. TQFP80 Package Dimensions

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

3. This package outline conforms to JEDEC MS-026, variant ADD.

4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020C specification for Small Body Components.

Dimension	Min	Тур	Мах								
A	0.70	0.75	0.80								
A1	0.00	_	0.05								
b	0.20	0.25	0.30								
A3		0.203 REF									
D	9.00 BSC										
е	0.40 BSC										
E	9.00 BSC										
D2	7.10	7.20	7.30								
E2	7.10	7.20	7.30								
L	0.35	0.40	0.45								
ааа		0.10									
bbb		0.10									
ссс		0.10									
ddd		0.05									
eee	0.08										
Nata											

### Table 7.1. QFN80 Package Dimensions

# Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

3. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

### Table 9.2. QFN64 PCB Land Pattern Dimensions

Dimension	Тур
C1	8.90
C2	8.90
E	0.50
X1	0.30
Y1	0.85
X2	7.30
Y2	7.30

### Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. This Land Pattern Design is based on the IPC-7351 guidelines.

3. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05mm.

4. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 μm minimum, all the way around the pad.

5. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.

6. The stencil thickness should be 0.125 mm (5 mils).

7. The ratio of stencil aperture to land pad size can be 1:1 for all pads.

8. A 3x3 array of 1.45 mm square openings on a 2.00 mm pitch can be used for the center ground pad.

9. A No-Clean, Type-3 solder paste is recommended.

10. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.



Figure 9.3. QFN64 Package Marking

The package marking consists of:

- PPPPPPPPP The part number designation.
- TTTTTT A trace or manufacturing code. The first letter is the device revision.
- YY The last 2 digits of the assembly year.
- WW The 2-digit workweek when the device was assembled.

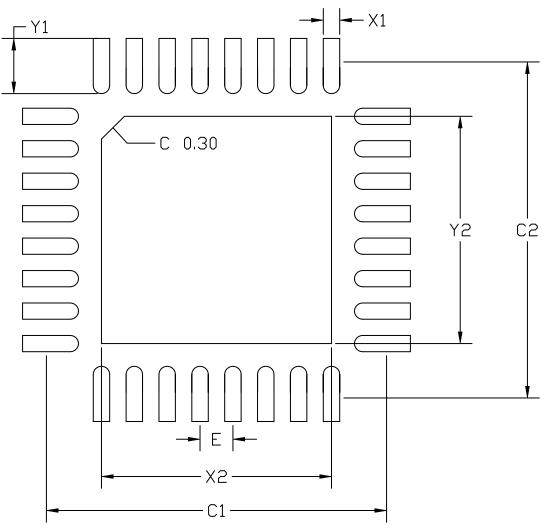


Figure 11.2. QFN32 PCB Land Pattern Drawing



Figure 11.3. QFN32 Package Marking

The package marking consists of:

- PPPPPPPPP The part number designation.
- TTTTTT A trace or manufacturing code. The first letter is the device revision.
- YY The last 2 digits of the assembly year.
- WW The 2-digit workweek when the device was assembled.